

TRANSMITTAL

Electronic Version v1.1

Stylesheet Version v1.1.0

Title of Invention	Methods of Treating a Silicon Carbide Substrate for Improved Epitaxial Deposition and Resulting Structures and Devices	
Application Number :		
Date :		
First Named Applicant:	Davis Andrew McClure	
Confirmation Number:		
Attorney Docket Number:	5000.238A	
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Submitted By:		Elec. Sign.
Philip Summa Registered Number: 31573		/Philip Summa/ Attorney

Documents being submitted:	Files
us-fee-sheet	5000238A-usfees.xml us-fee-sheet.xsl us-fee-sheet.dtd
us-request	5000238A-usrequ.xml us-request.dtd us-request.xsl
application-body	XMLspec238a-trans.xml us-application-body.xsl application-body.dtd wipo.ent mathml2.dtd mathml2-qname-1.mod isoamsa.ent isoamsb.ent isoamsc.ent isoamsn.ent isoamso.ent isoamsr.ent isogr3.ent isomfrk.ent isomopf.ent isomscr.ent isotech.ent isobox.ent isocyr1.ent isocyr2.ent isodia.ent isolat1.ent isolat2.ent isonum.ent isopub.ent mmlextra.ent mmlalias.ent soextblx.dtd FiguresPage1.tif FiguresPage2.tif FiguresPage3.tif
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